COMPACT ELECTRON ACCELERATOR FOR RADIATION TECHNOLOGIES

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Abstract

The concept of pulsed compact electron accelerator for radiation technologies is considered in the report. The main parameters of this accelerator are next: kinetic energy is 100-700 keV, pulse duration is 50-1000 nsec, beam current is 100-1000 A, repetition is 1-50 Hz, max dimensions of beam are 1x1 mxm..

1 INTRODUCTION

The development of radiation technologies (curing of composite materials, sterilisation of packaging materials, surface modification of materials, food irradiation and other) on the basis of electron beam made big progress in the understanding of main requirements on the electron accelerators [1]. The main principal question to accelerator for radiation technologies is regulation of kinetic energy and electron beam power [2]. The alternative methods of treatment for materials on the basis of plasma, UV, ozone and other allow to have only surface treatment of materials. The electron beam permits to have depth method of treatment of materials. But large spectra of irradiated products with different physical and chemical properties leads to design of electron accelerators with regulation of kinetic energy and beam power and consider the problem of irradiation in the combine with conveyer systems.

The analysis of different electron accelerators together with conditions for irradiation shows that the pulsed accelerators can be useful for first step of development of radiation technologies including research topics.

The variant of compact pulsed electron accelerator with regulation of kinetic energy and power beam is considered in the report.

2 MAIN PROCESSES OF DISSIPATION FOR BEAM ENERGY IN THE IRRADIATED PRODUCT

The general concept for interaction of electron beams with irradiated product for radiation technologies is dissipation of beam energy in this product.

The main demand for radiation technologies is homogeneous distribution of absorbed doses in the irradiated product.

The typical distribution of absorbed doses in irradiated product is given on Figure 1 for one side’s irradiation.

The value of average absorbed doses Daveon the level of 20% is [3]:

\[ D_{ave} = \frac{D_{max} + D_{min}}{2}, \]  

where: \( D_{max} \) is max absorbed dose, \( D_{min} \) is min absorbed doses, see Figure 1.

The optimal thickness \( L_{opt} \) of an irradiated product is determined by this distribution. The thickness of irradiated product is 0.05 – 2.0 mm for many materials with density to till 2 g/cc and kinetic energy of electrons 100 – 700 keV. The simple calculations of absorbed doses for materials with same thickness shows the level of doses about 50 – 200 kGy/pulse in case of using of pulsed high current accelerators. It allows to use pulsed high current electron accelerators in the development of radiation technologies. The average level of absorbed doses for many radiation technologies is about 10-150 kGy.

The other very important aspect of advantages of pulsed irradiation is short time of irradiation. The large absorbed doses leads to heating processes and non-control chemical reactions. It is very important for composition materials. The pulsed mode of accelerators allows the adiabatic irradiation. It is more simple in comparison with scanning DC and RF Linacs. The time of irradiation is main variable parameter for many industrial electron
accelerators. This time of irradiation (dissipation of beam energy) can be determines the thermal characteristics. The parameter for characterization of thermal properties of irradiated materials is local thermal time constant, which can be calculate by formula [4]:

\[ T(p) = \frac{2h^2rC}{l} \]  

(2)

Where: \( h \) is depth of penetration for electron beam in irradiated sample; \( rC/l \) is density, heat capacity and heat conductivity of irradiated materials.

According analysis of thermal distribution for many materials the time or irradiation for pulsed beam with duration about 50 - 1000 nsec is smaller in comparison with local thermal time constant (from ten to till hundred microseconds). This case we can consider as a adiabatic conditions and temperature of the product will have step distribution.

It is very important for multi-component materials with complex stoichiometry relationship.

3 CONCEPT OF PULSED ELECTRON ACCELERATOR FOR RADIATION TECHNOLOGIES

The main concept of pulsed electron accelerator for radiation technologies consists in the next:

- receiving of high absorbed doses in the small thickness of sample or product;
- adiabatic conditions of irradiation of samples or products;
- regulation of kinetic energy of electrons;
- regulation of beam power;
- large dimensions of electron beams;
- using of vacuum insulation for high voltage generator;
- simple cooling system for output window;
- using the output foil windows with protective coatings;
- on-line diagnostics of parameters for electron beams;
- low cost of accelerator;
- simple operation and reliable.

The compact pulsed electron accelerator consists from high voltage generator and electron source on the basis of vacuum diode or triode schemes. The structure diagram of accelerator is presented in Figure 2, 3.

The plasma cathode on the basis of discharge on the surface of dielectrics [5,6] allows to produce the large cross section cathode plasma and forming of electron with large dimensions, see Figure 4.

The triode geometry of electron gun with trigger electrode connected with resistors [7] allows to make regulation of accelerating voltage in 2 D geometry electrode system. Last leads to regulation of current density (power of beam). The general concept of this electron source is given on the Figure 5.
4 CONCLUSION

The concept of pulsed high current electron accelerator with regulations of main parameters allows to consider the development of pulsed accelerator for development for research and industrial applications.

5 REFERENCE